

NSF040120L4A0 1200 V, 40 mΩ, N-channel SiC MOSFET 15 August 2024

1. General description

The NSF040120L4A0 is a Silicon Carbide based 1200 V power MOSFET in a well-established 4-pin TO-247 plastic package for through hole PCB mounting technology. The excellent R_{DSon} temperature stability combined with its fast switching speed makes it a product of choice in high power and high voltage industrial applications like E-vehicle charging infrastructure, photovoltaic inverters and motor drives.

2. Features and benefits

- Excellent R_{DSon} temperature stability
- Very low switching losses
- Fast reverse recovery
- · Fast switching speed
- Temperature independent turn-off switching losses
- Very fast and robust intrinsic body diode
- Faster commutation and improved switching due to the additional Kelvin source pin

3. Applications

- E-vehicle charging infrastructure
- Photovoltaic inverters
- Switch mode power supply
- Uninterruptable power supply
- Motor drives

4. Quick reference data

| | ck reference data | | | | | | |
|-------------------|----------------------------------|---|-----|-----|-----|------|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| V _{DS} | drain-source voltage | | | - | - | 1200 | V |
| V _{GS} | gate-source voltage | | [1] | -10 | - | 22 | V |
| ID | drain current | T _c = 25 °C | [2] | - | - | 65 | А |
| | | T _c = 100 °C | [2] | - | - | 46 | А |
| I _{DM} | peak drain current | pulsed; t _p limited by T _j (max) | [3] | - | - | 160 | А |
| Static chara | cteristics | | | | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 15 V; I _D = 40 A; T _j = 25 °C | | - | 40 | 60 | mΩ |

[1] Recommended turn off gate voltage is -5 V to 0 V. Recommended turn on gate voltage is 15 V. Do not use with V_{GSon} < 13 V.

Limited by the maximum values of T_j and $R_{th(j-c)}$. [2]

[3] Designed value (not tested).

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5. Pinning information

| Pin | 2. Pinning info Symbol | Description | Simplified outline | Graphic symbol |
|-----|---------------------------|-----------------------------------|----------------------|-----------------------|
| 1 | D | drain | mb | |
| 2 | S | source | | |
| 3 | KS | Kelvin source | | D |
| 4 | G | gate | | |
| mb | D | mounting base; connected to drain | | G KS Baa-036675 |
| | | | TO-247-4 (SOT8071-1) | |

6. Ordering information

| Table 3. Ordering information | | | | | | |
|-------------------------------|----------|---|------------------|--|--|--|
| Type number | Package | kage | | | | |
| | Name | Description | Version | | | |
| NSF040120L4A0 | TO-247-4 | Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 4-lead TO-247-4 | <u>SOT8071-1</u> | | | |

7. Marking

| Table 4. Marking codes | | | | | |
|------------------------|--------------|--|--|--|--|
| Type number | Marking code | | | | |
| NSF040120L4A0 | NSF0412A0 | | | | |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|---------------------|-------------------------------|--|-----|-----|------|------|
| V _{DS} | drain-source voltage | | | - | 1200 | V |
| V _{GS} | gate-source voltage | | [1] | -10 | 22 | V |
| I _D | drain current | T _c = 25 °C | [2] | - | 65 | А |
| | | T _c = 100 °C | [2] | - | 46 | А |
| I _{DM} | peak drain current | pulsed; t _p limited by T _j (max) | [3] | - | 160 | А |
| P _{tot} | total power dissipation | T _c = 25 °C | [2] | - | 306 | W |
| Tj | junction temperature | | | -55 | 175 | °C |
| T _{stg} | storage temperature | | | -55 | 150 | °C |
| T _{sld(M)} | peak soldering temperature | | | - | 260 | °C |
| Source-drai | n diode | 1 | I | | | |
| Is | source current | T _c = 25 °C | [2] | - | 54 | А |
| I _{SM} | peak source current | pulsed; limited by T _j (max) | [3] | - | 120 | А |

[1] Recommended turn off gate voltage is -5 V to 0 V. Recommended turn on gate voltage is 15 V. Do not use with V_{GSon} < 13 V.

[2] Limited by the maximum values of T_j and $R_{th(j-c)}$.

[3] Designed value (not tested).

9. Thermal characteristics

Table 6. Thermal characteristics

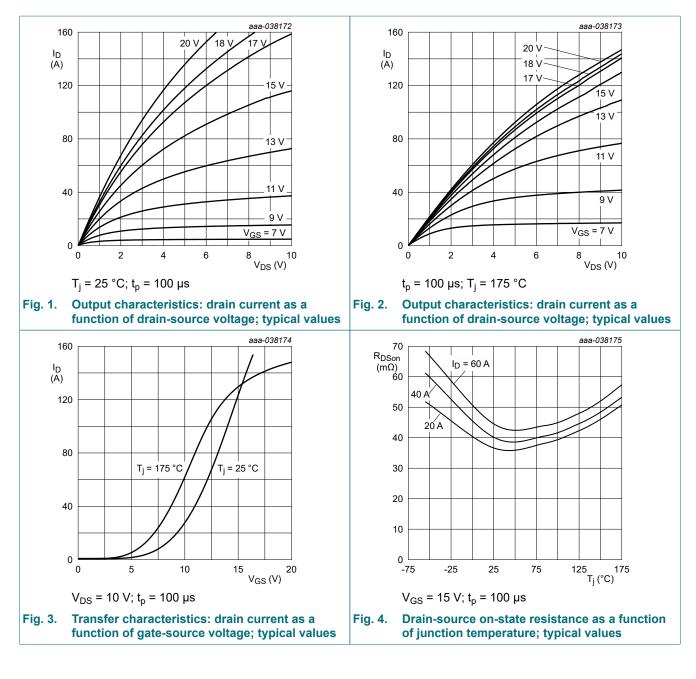
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--|------------|-----|------|------|------|
| R _{th(j-c)} | thermal resistance from junction to case | | - | 0.41 | 0.49 | K/W |

10. Characteristics

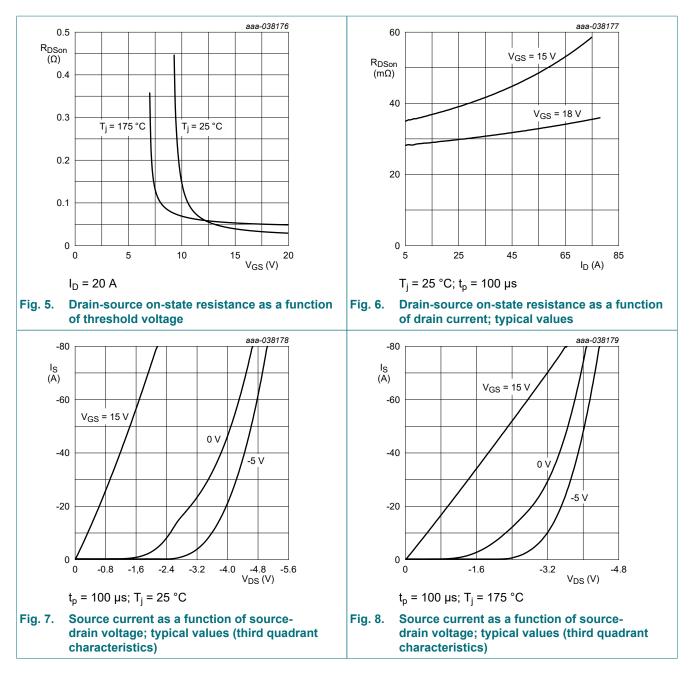
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------------------|-----------------------------------|--|-----|------|------|-----|------|
| Static chara | cteristics | | | | | | |
| V _{(BR)DSS} | drain-source breakdown voltage | I _D = 1 mA; V _{GS} = 0 V; T _j = 25 °C | | 1200 | - | - | V |
| V _{GS(th)} | gate-source threshold | I _D = 4 mA; V _{DS} = V _{GS} ; T _j = 25 °C | [1] | 1.7 | 2.3 | 2.9 | V |
| voltage | voltage | I _D = 20 mA; V _{DS} = V _{GS} ; T _j = 25 °C | [1] | - | 2.77 | - | V |
| I _{DSS} | drain leakage current | V _{DS} = 1200 V; V _{GS} = 0 V; T _j = 25 °C | | - | - | 100 | μA |
| I _{GSS} gate leakag | gate leakage current | V _{GS} = 22 V; V _{DS} = 0 V; T _j = 25 °C | | - | - | 100 | nA |
| | | V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C | | - | - | 100 | nA |
| R _{DSon} | drain-source on-state | V _{GS} = 15 V; I _D = 40 A; T _j = 25 °C | | - | 40 | 60 | mΩ |
| | resistance | V _{GS} = 15 V; I _D = 40 A; T _j = 125 °C | | - | 45 | - | mΩ |
| | | V _{GS} = 15 V; I _D = 40 A; T _j = 175 °C | | - | 53 | - | mΩ |
| | | V _{GS} = 18 V; I _D = 40 A; T _j = 25 °C | | - | 31 | - | mΩ |
| | | V _{GS} = 18 V; I _D = 40 A; T _j = 175 °C | | - | 49 | - | mΩ |
| 9 _{fs} | forward transconductance | $V_{DS} = 10 \text{ V}; \text{ I}_{D} = 40 \text{ A}; \text{ T}_{j} = 25 \text{ °C}$ | | - | 19 | - | S |
| R _{G(int)} | internal gate resistance | f = 0.5 MHz; T _j = 25 °C | | - | 2.3 | - | Ω |
| | aracteristics | - | | I | | | |
| Q _{G(tot)} | total gate charge | V _{DD} = 800 V; I _D = 40 A; V _{GS} = -5/+15 V; | | - | 95 | - | nC |
| Q _{GS} | gate-source charge | T _j = 25 °C | | - | 40 | - | nC |
| Q _{GD} | gate-drain charge | | | - | 30 | - | nC |
| C _{iss} | input capacitance | V _{DD} = 800 V; f = 0.5 MHz; V _{GS} = 0 V; | | - | 2600 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C | | - | 136 | - | pF |
| C _{rss} | reverse transfer capacitance | | | - | 6 | - | pF |
| t _{d(on)} | turn-on delay time | V _{DD} = 800 V; I _D = 40 A; R _{G(ext)} = 2.2 Ω; | | - | 22 | - | ns |
| t _r | rise time | L _L = 82 μH; V _{GS} = -5/+15 V; T _j = 25 °C | | - | 24 | - | ns |
| t _{d(off)} | turn-off delay time | | | - | 22 | - | ns |
| t _f | fall time | | | - | 8 | - | ns |
| E _{on} | turn-on switching loss | | | - | 607 | - | μJ |
| E _{off} | turn-off switching loss | | | - | 100 | - | μJ |
| Source-drai | n diode | 1 | | 1 | | | |
| V _{SD} | source-drain voltage | I _S = 40 A; V _{GS} = -5 V; T _j = 25 °C | | - | 4.4 | - | V |
| t _{rr} | reverse recovery time | V _{DD} = 800 V; I _S = 40 A; dI _S /dt = 5980 A/ | | - | 8 | - | ns |
| Q _r | recovered charge | μs; V _{GS} = -5 V; T _j = 25 °C | | - | 103 | - | nC |

[1] Measured according to JEP183.

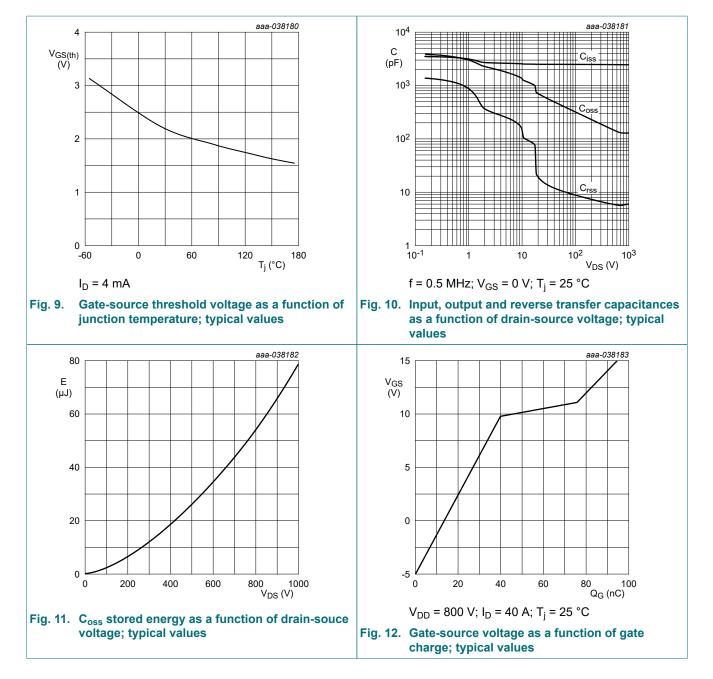
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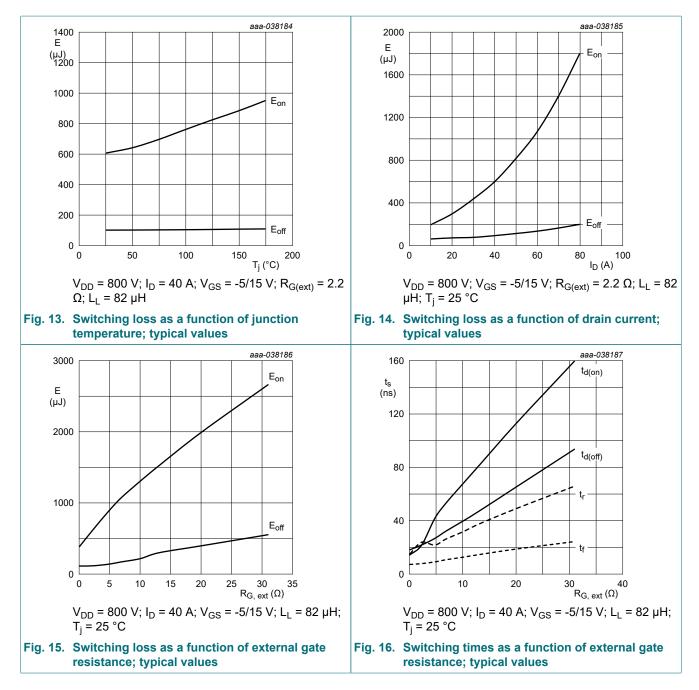
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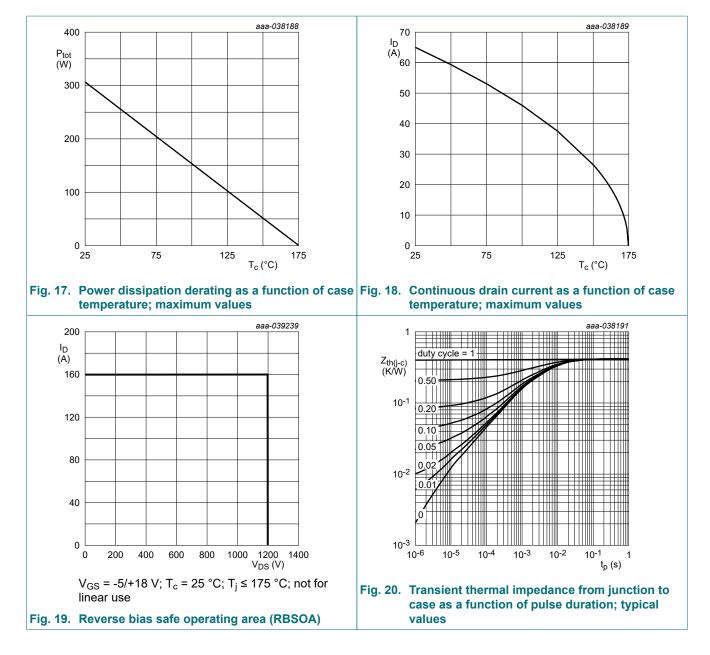
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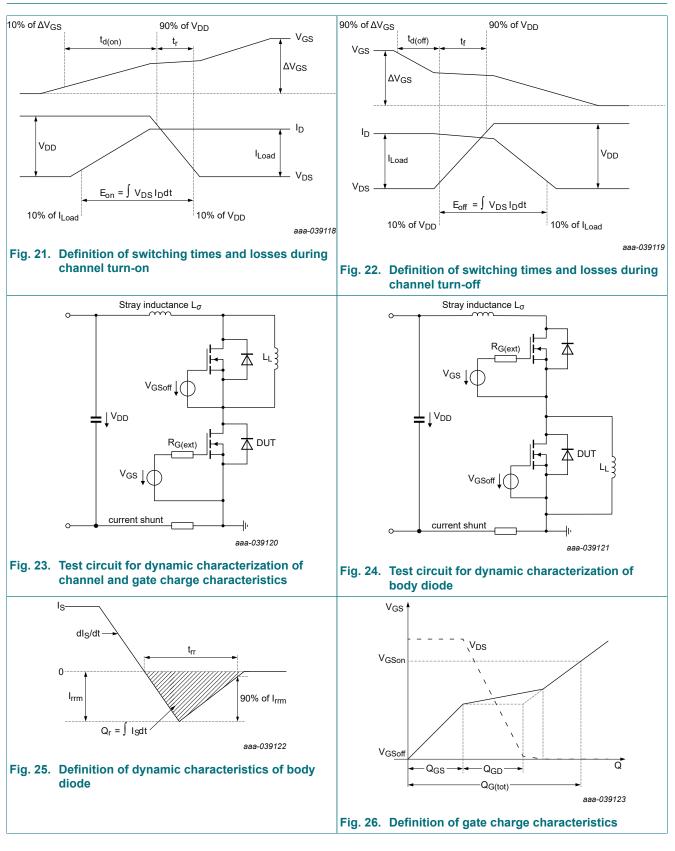
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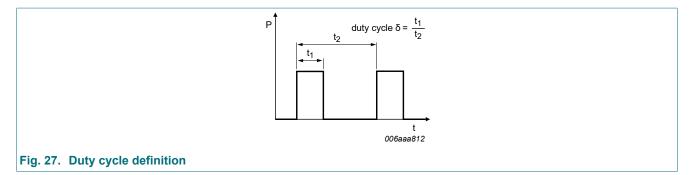
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11. Test information

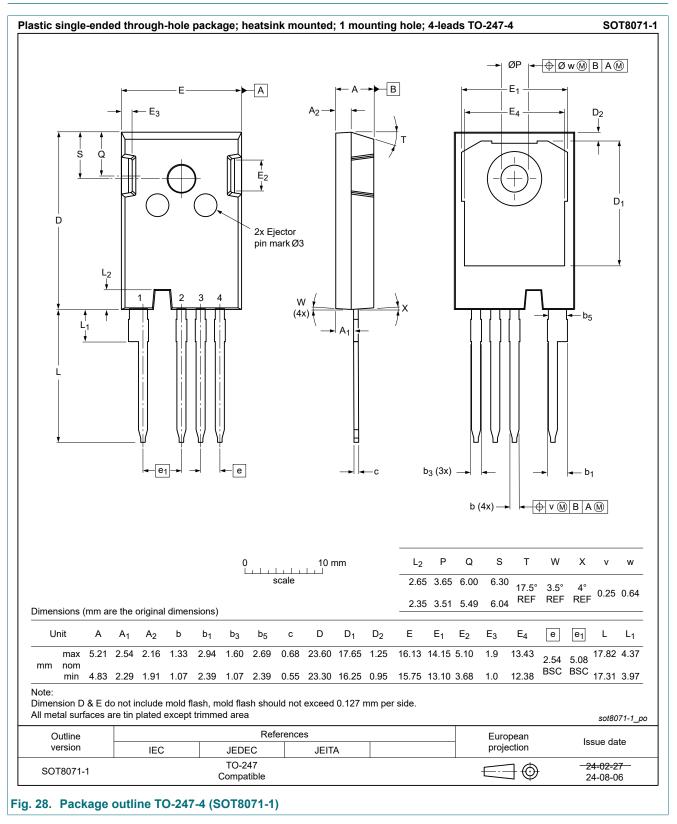


1200 V, 40 mΩ, N-channel SiC MOSFET



1200 V, 40 mΩ, N-channel SiC MOSFET

12. Package outline



13. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------------|---|------------------------|---------------|----------------------|
| NSF040120L4A0 v.5 | 20240815 | Product data sheet | - | NSF040120L4A0 v.4 |
| Modifications: | Characteristics at V Characteristics at V Characteristics: Figure Section Test information | ure 19 exchanged | | |
| NSF040120L4A0 v.4 | 20240202 | Product data sheet | - | NSF040120L4A0 v.3 |
| NSF040120L4A0 v.3 | 20231228 | Preliminary data sheet | - | NSF040120L4A0 v.2 |
| | | Objective data aboat | _ | NSF040120L4A0 v.1 |
| NSF040120L4A0 v.2 | 20230905 | Objective data sheet | - | 1101 04012024/10 1.1 |

14. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|-----------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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- [2] The term 'short data sheet' is explained in section "Definitions".
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Contents

| 1. General description | 1 |
|----------------------------|----|
| 2. Features and benefits | 1 |
| 3. Applications | 1 |
| 4. Quick reference data | 1 |
| 5. Pinning information | 2 |
| 6. Ordering information | 2 |
| 7. Marking | 2 |
| 8. Limiting values | 3 |
| 9. Thermal characteristics | 3 |
| 10. Characteristics | 4 |
| 11. Test information | |
| 12. Package outline | 12 |
| 13. Revision history | 13 |
| 14. Legal information | |
| | |

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